

## 3.0mmx1.0 mm RIGHT ANGLE SMD **CHIP LED LAMP**

Part Number: KPA-3010SECK

Super Bright Orange

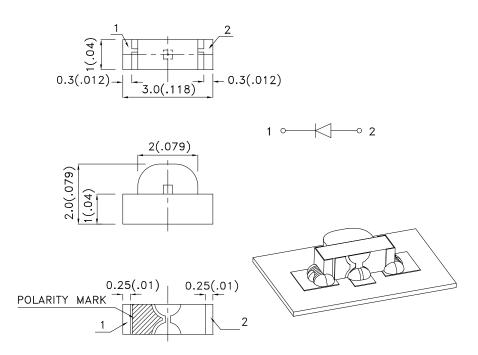
#### **Features**

- 3.0mmx1.0mm right angle SMT LED, 2.0mm thickness.
- Low power consumption.
- Wide viewing angle.
- Ideal for back light and indicator.
- Various colors and lens types available.
- Package: 2000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

## Description

The Super Bright Orange device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

# **Package Dimensions**



- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.15(0.006") unless otherwise noted.
- The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
   The device has a single mounting surface. The device must be mounted according to the specifications.

SPEC NO: DSAB7756 **REV NO: V.12** DATE: MAY/03/2010 APPROVED: WYNEC CHECKED: Allen Liu **DRAWN: SHANW** 



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## **Selection Guide**

Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA		Viewing Angle [1]
		,	Min.	Тур.	201/2
KPA-3010SECK	Super Bright Orange (AlGaInP)	WATER CLEAR	110	300	120°

#### Notes

- 1.  $\theta$ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
- 2. Luminous intensity/ luminous Flux: +/-15%.

# Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Orange	610		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Orange	601		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Orange	29		nm	IF=20mA
С	Capacitance	Super Bright Orange	15		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Orange	2.1	2.5	V	IF=20mA
lR	Reverse Current	Super Bright Orange		10	uA	V <sub>R</sub> =5V

#### Notes:

- 1.Wavelength: +/-1nm.
- 2. Forward Voltage: +/-0.1V.

# Absolute Maximum Ratings at TA=25°C

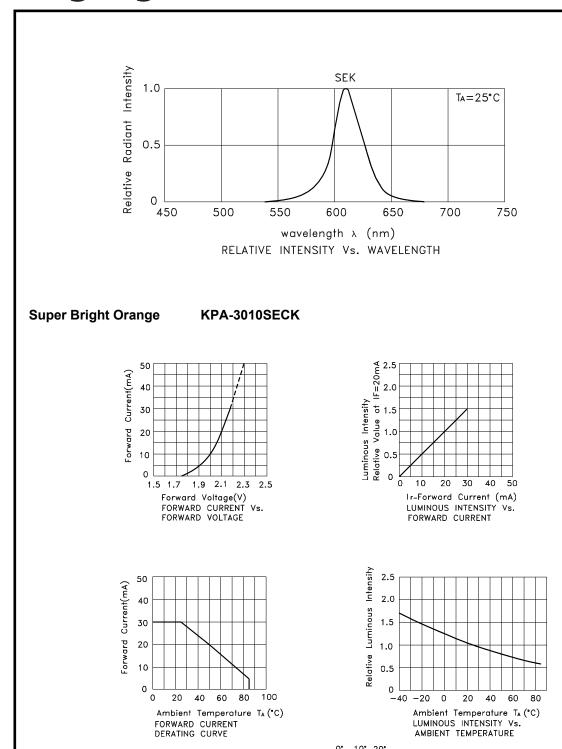
Parameter	Super Bright Orange		
Power dissipation	75	mW	
DC Forward Current	30	mA	
Peak Forward Current [1]	195	mA	
Reverse Voltage	5	V	
Operating Temperature	-40°C To +85°C		
Storage Temperature	-40°C To +85°C		

#### Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

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SPATIAL DISTRIBUTION

0.7

30°

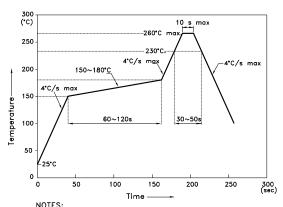
40° 50° 60° 70° 80°

90°

## **KPA-3010SECK**

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.

Reflow Soldering Profile For Lead-free SMT Process.



- NOTES:

  1.We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.

  2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
- to high temperature.

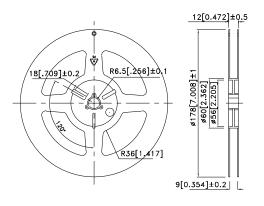
  3.Number of reflow process shall be 2 times or less.

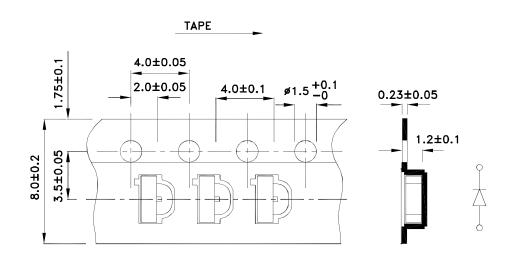
# Recommended Soldering Pattern (Units: mm; Tolerance: ± 0.1)

# 0.9

# Tape Dimensions (Units : mm)

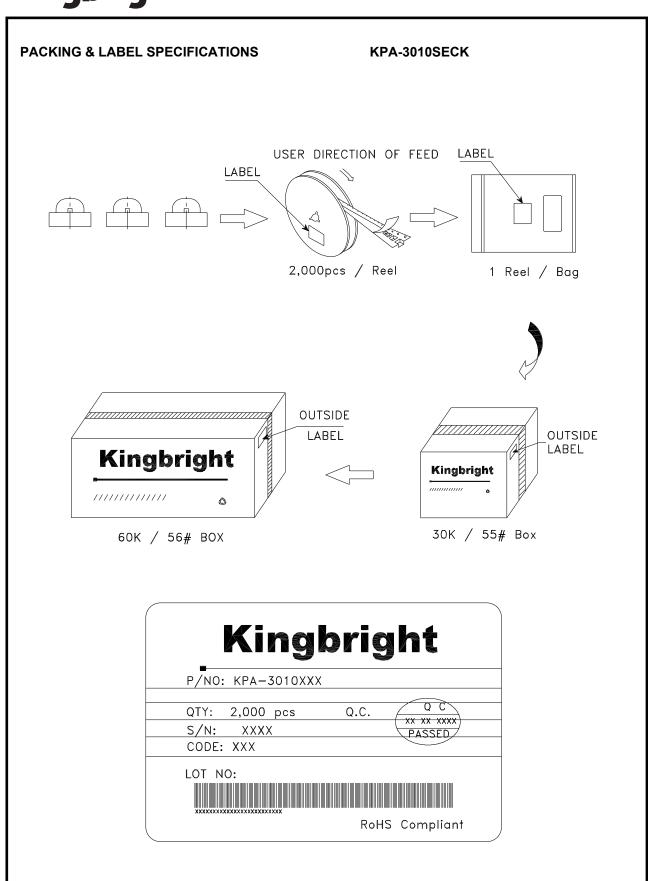
## **Reel Dimension**





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